

oducts	Home ▶ 2N6276 (#23538) 2N6276 (#23538)						Related Links
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	Electrical Rating	Symbol	Min	Тур	Max	Unit	Sales Contacts RFQ/Samples
	Collector to Emitter Saturation Voltage	V <sub>CE(sat)</sub>			3.00	V	RFQ/Samples
	DC Current Gain	HFE	30.00		120.00		
	Maximum Electrical Rating			Min Typ		Unit	
	Breakdown Voltage, Collector-Base (Emitter Open)	_	/BR(CBO)		160.00 50.00	V	
	Collector Current (dc) Collector-Emitter Voltage (Base Open)		c		120.00	V	
	Emitter-Base Voltage (Collector Open)	_	/ <sub>EBO</sub>		6.00	V	
	Power Dissipation, Total		PT		250.00	W	
	<ul> <li>This part can be found in the following product</li> <li>Discretes &gt; Transistors &gt; BJT( BiPolar Junction Tra</li> <li>Non-Radiation Hardened Devices &gt; Transistors &gt; E</li> </ul>	ansistor) 🕨	PNP Transis		NPN Transis	stor	

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